



# DEPARTMENT OF PHYSICS AND NANOTECHNOLOGY SRM INSTITUTE OF SCIENCE AND TECHNOLOGY

### 18PYB103J –Semiconductor Physics

**Module-V Lecture-9** 

Characterization Techniques-X-Ray Diffraction-Powder Method



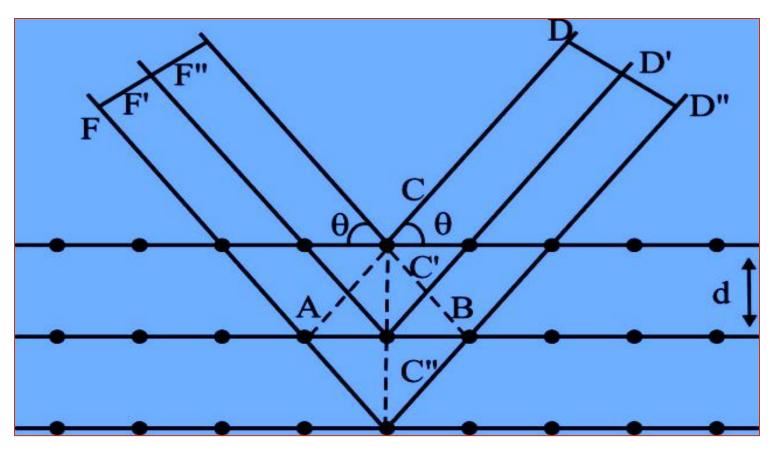


# **X-Ray Diffraction**

- >X-ray diffraction is used for the complete determination of molecular structure of crystals.
- Every lattice plane in a crystal behaves like diffraction grating, on the exposure of X-rays.
- The position of the spectral lines when diffracted depends on the distance between successive lines; similarly the nature of the X-ray diffracted by a crystal is determined by the spacing between successive planes.











If a beam of monochromatic X-rays is incident on a crystal at an angle  $\theta$ , some of the rays will be diffracted by the layers of atoms in the crystal.

The path length FC'D is larger than FCD by AC'B which is equal to 2AC', and since  $AC' = d\sin\theta$ , the path difference is  $2d\sin\theta$ .

This difference in path length must be an integral number (n) of wavelengths ( $\lambda$ ) for maximum diffraction of X-rays with destructive interference. Thus

 $n\lambda = 2d\sin\theta$ 

which is the **Bragg's equation**.

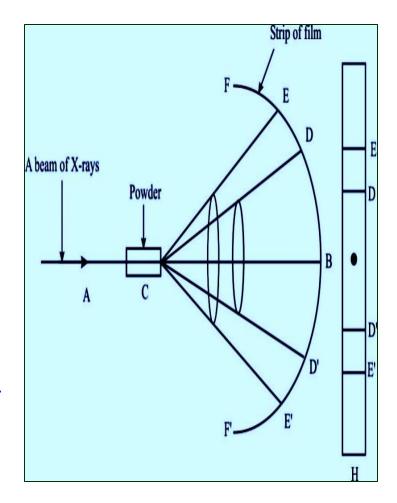
With the help of the Bragg's equation it is possible to determine the spacing d between successive lattice planes, if  $\lambda$  is known and  $\theta$  is measured.



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#### The powder method:

- A narrow beam of monochromatic X-rays fall on the finely powdered specimen to be examined, and the diffracted rays are passed on to a strip of film which almost completely surrounds the specimen.
- The random orientation of crystals produces diffraction rings.
- This method is commonly used for identification purposes by comparing the data with the standard files available.
- For a cubic crystal the identification of lines in the powder photograph is simple compared to other types.







# **Application of XRD**

- \*XRD is a nondestructive technique
- \*To identify crystalline phases and orientation
- \*To determine structural properties: Lattice parameters (10-4Å), strain, grain size, phase composition.
- \*To measure thickness of thin films and multi-layers
- \*\*To determine atomic arrangement